Important new developments

Atlas 46 - negative photoresists up to 100 µm stable resist structures

AR-N 4600

EOS 72 - positive e-beam resist, CAR high resolution, highest sensitive

SX AR-P 7200

Phoenix 81 - thermostructurable positive resist for NanoFrazor application

AR-P 8100

Medusa 82 - negative e-beamres. adjusted HSQ, more prozess stability or. sensitive, high resolution

SX AR-N 8200, 8250

Protective coating, 40% KOH-, 50% HF-resist.

SX AR-PC 5000/41

Temperature-stable negative photoresist up to 300 °C, suitable für 2-layer systems

SX AR-N 4340/7

Fluorescent photo- and e-beam resists

SX AR-P/N 8500

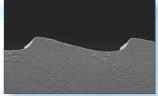
3 different fluorescent atlas structures

AR-N 2220 resist structures in 200 um

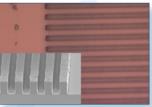
60-150 nm squares (100 nm height) on glass

with AR-N 7700.08 and AR-PC 5091.02

deep etched trenches



Sinusoidal profiles with AR-N 7720.30



Atlas 46 R 5µm line & space, structures are easy removable



Thermostable 2-Layer lift-off systems with AR-BR 5460 and SX AR-N 4340/7



Company for chemical products for microstructures

Foundation: Oktober 16 1992, HRB 7805 AG Frankfurt (Oder)

Managing directors: Brigitte and Matthias Schirmer

Integrated management system: Quality management DIN EN ISO 9001:2015, Eco-Management DIN EN ISO 14001:2015

Memberships in science- and trade associations: Silicon Saxony, ig Brandenburg, Verein Sichere Identität, IVAM

Prizes & Awards: Ludwig-Erhard-Preis Qualitätspreis Berlin-Brandenburg Innovation Prize Brandenburg Deutschlands Kundenchampions Deutschlands Mitarbeiterchampions Exzellente Wissensorganisation Technologietransferpreis Brandenburg Zukunftspreis Ostbrandenburg Entrepreneur of the Federal State of Brandenburg







Resists and Process chemicals for optical and electron beam lithography



Innovation, creativity, customer-specific solutions







ALLRESIST Innovation Creativity Costumér-specific solutions

Product profile ALLRESIST

Development, production and distribution of photo- & e-beam resists as well as process chemicals for the manufacturing of electronic components (chips)

- Wide range of products resists for (almost) all standard technologies
- Process-specific resists according to customer's requests für industrial - unique selling proposition
- Development of innovative products for new application and technologies
- Particular focus on industrial reseach, project development in cooperation with research
- Individual, competent product- and technology consulting
- Short delivery times (products in stock are delivered promptly)
- Customer-oriented package sizes of 250 ml, test samples of 100 ml



Evaluation of customer requirements and new products. Strategic discussion in the steering committ

Customer-specific resists

ALLRESIST will take your special demands into consideration already during conception and development of new resists.

For industry customers, Allresist develops tailor-made resists or modifies standard resists according to the respective technology requirements.



Introduction of customer-specific resists

You will find detailed product information together with a collection of Resist Wiki, AR NEWS, FAQ and EU safety data sheets at www.allresist.com. In addition to our resists, we offer thinner, developer, stopper, remover and adhesion promoter as optimally resist-adapted process chemicals. Allresist continuously develops new products. Please contact us! As of 01/21

Product summary

g-line photoresists,

Positive

Special systems

photoresists

Neg.

Spray	coating	tor	various	applications	

Mask production, fine gradations, high resolution 1.0:0.6:0.1

Thick resist of high dimens. accuracy up to 40/100/20 µm

Wide process range, high resolution

High contrast, highest resolution, sub-µm

Undercut structures (one layer lift-off)

Protective coating, 40% KOH-etch-stable

Conductive protective coatings for e-beam

Spray coating for various applications

Thick films up to $100/50/20 \mu m$

i-line. e-beam

for excellent resolution

Bottom resist for 2-layer lift-off system (pos./neg.)

Highest sensitivity, high resolution, i-line, g-line

easy removal, Profiles with high edge steepness

Copolymer PMMA/MA 33%, highest resolution

PMMA 50K, 200K, 600K, 950K, highest resolution

chlorobenzene (1), anisole (2), ethyl lactate (9)

Styrene acrylate, highest resolution, high sensiti-

[0.5 - 10] AR-P 1210, 1220, 1230

Do [µm] 4000 rpm

10:5:10

2.0:1.4

5.0:1.0

2.2 ; 2.8

0.04

1.0 ; 0.5

[0.5 - 10]

50:25:10

(1000 rpm)

0.09 1.75

0.01 1.87

0.08 ... 0.80

350 rpm: 45-95

0.4:0.1

0.4:0.1

1.4:0.25

0.4:0.2:0.1

1.4

1.4

AR-P 3110, 3120, 3170

AR-P 3210, 3250, 3220

AR-P 3510 (T), 3540 (T)

AR-P 3740

AR-P 5320, 5350

Electra 92

AR-BR 5460, 5480

AR-N 4340

CAR 44 AR-N 4400-50. -25

AR-P 641-671, 632-672

CSAR 62 AR-P 6200

AR-P 6510

10 nm trenches with AR-P 6200.09 (CSAR 62)

AR-PC 504, 5040

AR-PC 5090, 5091

AR-P 2210, 2220, 2230

AR-N 4400-10, -05

AR-P 617

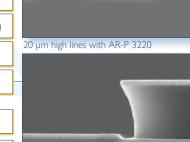
AR-P 639-679

AR-N 7500

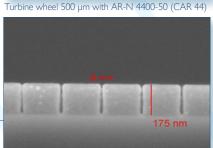
AR-N 7520 (new)

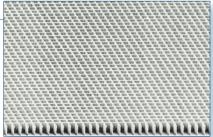
AR-N 7700

AR-N 7720



Lift-off-structures with AR-P 5350





70 nm structures with AR-N 7500.1



Neg. (

Mix&match, etching-resistant, high resolution

vity, very plasma etching-resistant

Thick PMMA films up to 100 µm, deep UV

Mix&match, etching-resistant, highest resolution

CAR, high resolution, steep gradation, digit. image

CAR, high resolution, low contrast